19-3162; Rev 3; 6/11



### **General Description**

The MAX3738 is a +3.3V laser driver designed for multirate transceiver modules with data rates from 155Mbps to 4.25Gbps. Lasers can be DC-coupled to the MAX3738 for reduced component count and ease of multirate operation.

Laser extinction ratio control (ERC) combines the features of automatic power control (APC), modulation compensation, and built-in thermal compensation. The APC loop maintains constant average optical power. Modulation compensation increases the modulation current in proportion to the bias current. These control loops, combined with thermal compensation, maintain a constant optical extinction ratio over temperature and lifetime.

The MAX3738 accepts differential data input signals. The wide 5mA to 60mA (up to 85mA AC-coupled) modulation current range and up to 100mA bias current range, make the MAX3738 ideal for driving FP/DFB lasers in fiber optic modules. External resistors set the required laser current levels. The MAX3738 provides transmit disable control (TX\_DISABLE), single-point fault tolerance, bias-current monitoring, and photocurrent monitoring. The device also offers a latched failure output (TX\_FAULT) to indicate faults, such as when the APC loop is no longer able to maintain the average optical power at the required level. The MAX3738 is compliant with the SFF-8472 transmitter diagnostic and SFP MSA timing requirements.

The MAX3738 is offered in a 4mm x 4mm, 24-pin thin QFN package and operates over the extended -40°C to  $+85^{\circ}$ C temperature range.

Multirate OC-3 to OC-48 FEC Transceivers Gigabit Ethernet SFF/SFP and GBIC Transceivers

**Applications** 

1Gbps/2Gbps/4Gbps Fibre Channel SFF/SFP and GBIC Transceivers

Typical Application Circuit appears at end of data sheet.

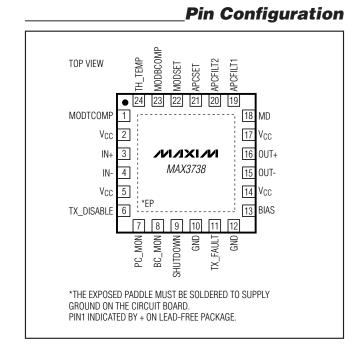
### Features

- Single +3.3V Power Supply
- ♦ 47mA Power-Supply Current
- ♦ 85mA Modulation Current
- 100mA Bias Current
- Automatic Power Control (APC)
- Modulation Compensation
- On-Chip Temperature Compensation
- Self-Biased Inputs for AC-Coupling
- ♦ Ground-Referenced Current Monitors
- Laser Shutdown and Alarm Outputs
- Enable Control and Laser Safety Feature

### **Ordering Information**

| PART        | TEMP RANGE     | PIN-PACKAGE     |
|-------------|----------------|-----------------|
| MAX3738ETG  | -40°C to +85°C | 24 Thin QFN-EP* |
| MAX3738ETG+ | -40°C to +85°C | 24 Thin QFN-EP* |

+Denotes a lead(Pb)-free/RoHS-compliant package. \*EP = Exposed pad.



### 

\_ Maxim Integrated Products 1

For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

### **ABSOLUTE MAXIMUM RATINGS**

| Supply Voltage V <sub>CC</sub> 0.5V to +6.0V  |
|---|
| IN+, IN-, TX_DISABLE, TX_FAULT, SHUTDOWN,   |
| BC_MON, PC_MON, APCFILT1, APCFILT2,   |
| MD, TH_TEMP, MODTCOMP, MODBCOMP,  |
| MODSET, and APCSET Voltage0.5V to (V <sub>CC</sub> + 0.5V)  |
| OUT+, OUT-, BIAS Current20mA to +150mA  |
| Continuous Power Dissipation ( $T_A = +70^{\circ}C$ )   |
| TQFN (derate 27.8mW/°C above +70°C)2222mW   |
| MD, TH_TEMP, MODTCOMP, MODBCOMP,<br>MODSET, and APCSET Voltage0.5V to ( $V_{CC}$ + 0.5V)<br>OUT+, OUT-, BIAS Current20mA to +150mA<br>Continuous Power Dissipation ( $T_A$ = +70°C) |

| Operating Junction Temperature Range | 55°C to +150°C |
|--------------------------------------|----------------|
| Storage Temperature Range            | 55°C to +150°C |
| Lead Temperature (soldering, 10s)    | +300°C         |
| Soldering Temperature (reflow)       |                |
| Lead(Pb)-free                        | +260°C         |
| Containing lead(Pb)                  | +240°C         |

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ELECTRICAL CHARACTERISTICS**

(V<sub>CC</sub> = +2.97V to +3.63V,  $T_A$  = -40°C to +85°C. Typical values are at V<sub>CC</sub> = +3.3V, I<sub>BIAS</sub> = 60mA, I<sub>MOD</sub> = 60mA, T<sub>A</sub> = +25°C, unless otherwise noted.) (Notes 1, 2)

| PARAMETER                           | SYMBOL | CONDITIONS   |                             | MIN | ТҮР  | МАХ                                      | UNITS  |
|-------------------------------------|--------|--|-----------------------------|-----|------|--|--------|
| POWER SUPPLY                        | •      |  |                             |     |      |  |        |
| Supply Current                      | ICC    | (Note 3)   |                             |     | 47   | 60                                       | mA     |
| Power-Supply Noise Rejection        | PSNR   | f ≤ 1MHz, 100n   | nAp-p (Note 4)              |     | 33   |  | dB     |
| I/O SPECIFICATIONS                  | •      |  |                             |     |      |  |        |
| Differential Input Swing            | VID    | DC-coupled, Fi   | gure 1                      | 0.2 |      | 2.4                                      | VP-P   |
| Common-Mode Input                   | VCM    |  |                             | 1.7 |      | V <sub>CC</sub> -<br>V <sub>ID</sub> / 4 | V      |
| LASER BIAS                          |        |  |                             | •   |      |  |        |
| Bias-Current-Setting Range          |        |  |                             | 1   |      | 100                                      | mA     |
| Bias Off Current                    |        | TX_DISABLE =   | high                        |     |      | 0.1                                      | mA     |
| Bias-Current Monitor Ratio          |        | IBIAS / IBC_MON  |                             | 62  | 76   | 90                                       | mA/mA  |
| LASER MODULATION                    |        |  |                             |     |      |  |        |
| Modulation Current-Setting<br>Range | IMOD   | (Note 5)   |                             | 5   |      | 85                                       | mA     |
| Output Edge Speed                   |        | 20% to 80%<br>(Notes 6, 7) 5mA ≤ I <sub>MOD</sub> ≤ 85mA |                             |     | 65   | 80                                       | ps     |
| Output Overshoot/Undershoot         |        |  |                             |     | ±6   |  | %      |
| Random Jitter                       |        | (Notes 6, 7)   |                             |     | 0.62 | 1.3                                      | psrms  |
|                                     |        | 2.7Gbps, 5mA   | ≤ I <sub>MOD</sub> ≤ 85mA   |     | 18   | 40                                       | ĺ      |
| Deterministic Jitter (Notes 6, 8)   |        | 1.25Gbps, 5mA ≤ I <sub>MOD</sub> ≤ 85mA                  |                             |     | 20   | 41                                       | ]      |
| Deterministic Jitter (Notes 6, 6)   |        | 622Mbps, $5mA \le I_{MOD} \le 85mA$                      |                             |     | 24   | 46                                       | psp-p  |
|                                     |        | 155Mbps, $5mA \le I_{MOD} \le 85mA$                      |                             |     | 45   | 100                                      |        |
| Modulation-Current Temperature      |        | (Note 6) $5mA \le I_{MOD} \le 10mA$                      |                             |     | ±175 | ±600                                     | ppm/°C |
| Stability                           |        |  | $10mA \le I_{MOD} \le 85mA$ |     | ±125 | ±480                                     |        |
| Modulation-Current-Setting Error    |        | 15 $\Omega$ load,  | $5mA \le I_{MOD} \le 10mA$  |     |      | ±20                                      | %      |
| Modulation-Current-Setting End      |        | $T_A = +25^{\circ}C$                                     | $10mA < I_{MOD} \le 85mA$   |     |      | ±15                                      | /0     |
| Modulation Off Current              |        | TX_DISABLE =   | high                        |     |      | 0.1                                      | mA     |

### **ELECTRICAL CHARACTERISTICS (continued)**

(V<sub>CC</sub> = +2.97V to +3.63V, T<sub>A</sub> = -40°C to +85°C. Typical values are at V<sub>CC</sub> = +3.3V, I<sub>BIAS</sub> = 60mA, I<sub>MOD</sub> = 60mA, T<sub>A</sub> = +25°C, unless otherwise noted.) (Notes 1, 2)

| PARAMETER   | SYMBOL          | CONDITIONS  | MIN                   | ТҮР  | MAX  | UNITS  |
|---|-----------------|---|-----------------------|------|------|--------|
| AUTOMATIC POWER AND EXT                                       | INCTION RAT     | IO CONTROLS   | •                     |      |      | •      |
| Monitor-Diode Input Current<br>Range                          | I <sub>MD</sub> | Average current into the MD pin   | 18                    |      | 1500 | μA     |
| MD Pin Voltage  |                 |   |                       |      | 1.4  | V      |
| MD Current Monitor Ratio                                      |                 | IMD / IPC_MON   | 0.85                  | 0.93 | 1.15 | mA/mA  |
| APC Loop Time Constant  |                 | $C_{APC_FILT} = 0.01 \mu F$ , $\Delta I_{MD} / \Delta I_{BIAS} = 1/70$        |                       | 3.3  |      | μs     |
| APC Setting Stability   |                 | (Note 6)  |                       | ±100 | ±480 | ppm/°C |
| APC Setting Accuracy  |                 | $T_{A} = +25^{\circ}C$  |                       |      | ±15  | %      |
| I <sub>MOD</sub> Compensation-Setting<br>Range by Bias        | К               | $K = \Delta I_{MOD} / \Delta I_{BIAS}$  | 0                     |      | 1.5  | mA/mA  |
| I <sub>MOD</sub> Compensation-Setting<br>Range by Temperature | TC              | $TC = \Delta I_{MOD} / \Delta T \text{ (Note 6)}$                             | 0                     |      | 1.0  | mA/°C  |
| Threshold-Setting Range for<br>Temperature Compensation       | T <sub>TH</sub> | (Note 6)  | +10                   |      | +60  | °C     |
| LASER SAFETY AND CONTROL                                      | L               |   | •                     |      |      | •      |
| Bias and Modulation Turn-Off<br>Delay                         |                 | $C_{APC\_FILT} = 0.01 \mu F, \Delta I_{MD} / \Delta I_{BIAS} = 1/80$ (Note 6) |                       |      | 5    | μs     |
| Bias and Modulation Turn-On<br>Delay                          |                 | $C_{APC\_FILT} = 0.01 \mu F, \Delta I_{MD} / \Delta I_{BIAS} = 1/80$ (Note 6) |                       |      | 600  | μs     |
| Threshold Voltage at Monitor                                  | VREF            | Figure 5  | 1.14                  | 1.3  | 1.39 | V      |
| INTERFACE SIGNALS   | ·               |   | ·                     |      |      | •      |
| TX_DISABLE Input High   | VHI             |   | 2.0                   |      |      | V      |
| TX_DISABLE Input Low  | VLO             | $R_{PULL} = 45k\Omega$ (typ)  |                       |      | 0.8  | V      |
| TX_DISABLE Input Current                                      |                 | V <sub>HI</sub> = V <sub>CC</sub>   |                       |      | 15   | μA     |
|   |                 | V <sub>LO</sub> = V <sub>GND</sub> -70 -7                                     |                       | -140 |      |        |
| TX_FAULT Output Low   |                 | Sinking 1mA, open collector   |                       |      | 0.4  | V      |
| Shutdown Output High  |                 | Sourcing 100µA  | V <sub>CC</sub> - 0.4 |      |      | V      |
| Shutdown Output Low   |                 | Sinking 100µA   |                       |      | 0.4  | V      |

Note 1: AC characterization is performed using the circuit in Figure 2 using a PRBS 2<sup>23</sup> - 1 or equivalent pattern.

Note 2: Specifications at -40°C are guaranteed by design and characterization.

Note 3: Excluding IBIAS and IMOD. Input data is AC-coupled. TX\_FAULT open, SHUTDOWN open.

Note 4: Power-supply noise rejection (PSNR) =  $20\log_{10}(V_{noise (on VCC)} / \Delta V_{OUT})$ . V<sub>OUT</sub> is the voltage across the 15 $\Omega$  load when IN+ is high.

**Note 5:** The minimum required voltage at the OUT+ and OUT- pins is +0.75V.

Note 6: Guaranteed by design and characterization.

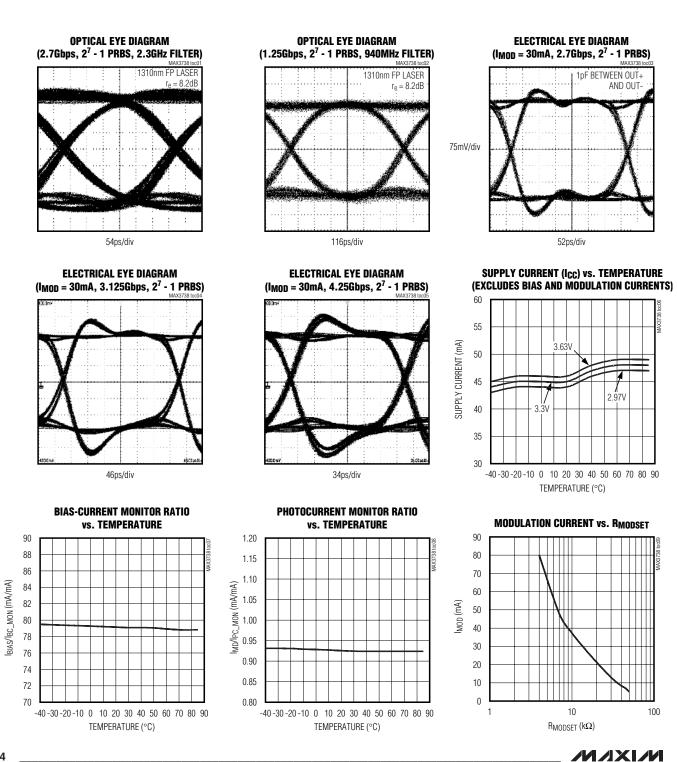
Note 7: Tested with 00001111 pattern at 2.7Gbps.

Note 8: DJ includes pulse-width distortion (PWD).

MIXI/N

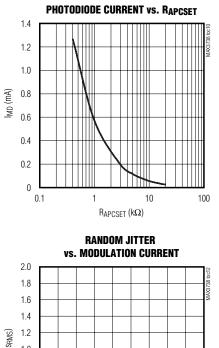
**Typical Operating Characteristics** 

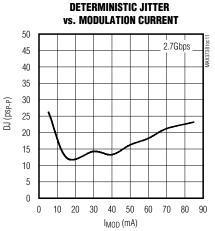
 $(V_{CC} = +3.3V, C_{APC} = 0.01\mu$ F,  $I_{BIAS} = 20$ mA,  $I_{MOD} = 30$ mA,  $T_A = +25$ °C, unless otherwise noted.)



### **Typical Operating Characteristics (continued)**

(V<sub>CC</sub> = +3.3V, C<sub>APC</sub> =  $0.01\mu$ F, I<sub>BIAS</sub> = 20mA, I<sub>MOD</sub> = 30mA, T<sub>A</sub> = +25°C, unless otherwise noted.)

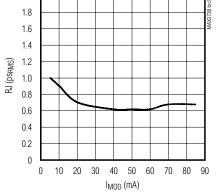




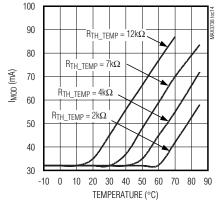


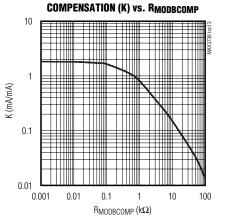
MAX3738



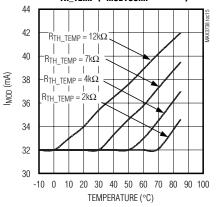








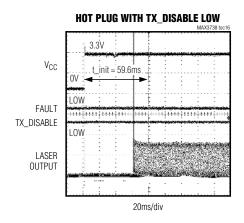
**TEMPERATURE COMPENSATION vs. R**TH\_TEMP (**R**MODTCOMP =  $10k\Omega$ )

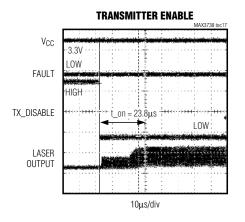


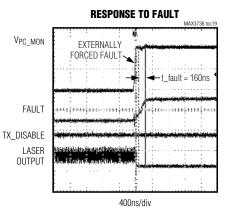
MIXIM

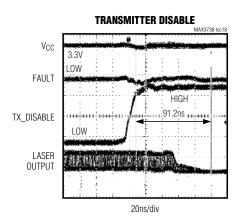
### **Typical Operating Characteristics (continued)**

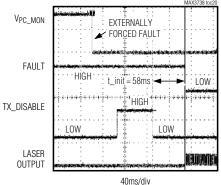
(V<sub>CC</sub> = +3.3V, C<sub>APC</sub> =  $0.01\mu$ F, I<sub>BIAS</sub> = 20mA, I<sub>MOD</sub> = 30mA, T<sub>A</sub> = +25°C, unless otherwise noted.)









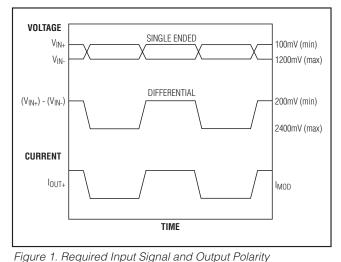


#### FAULT RECOVERY TIME

## \_\_\_\_Pin Description

| PIN          | NAME       | FUNCTION   |
|--------------|------------|--|
| 1            | MODTCOMP   | Modulation-Current Compensation from Temperature. A resistor at this pin sets the temperature coefficient of the modulation current when above the threshold temperature. Leave open for zero temperature compensation.              |
| 2, 5, 14, 17 | Vcc        | +3.3V Supply Voltage   |
| 3            | IN+        | Noninverted Data Input   |
| 4            | IN-        | Inverted Data Input  |
| 6            | TX_DISABLE | Transmitter Disable, TTL. Laser output is disabled when TX_DISABLE is asserted high or left unconnected. The laser output is enabled when this pin is asserted low.  |
| 7            | PC_MON     | Photodiode-Current Monitor Output. Current out of this pin develops a ground-referenced voltage across an external resistor that is proportional to the monitor diode current.   |
| 8            | BC_MON     | Bias-Current Monitor Output. Current out of this pin develops a ground-referenced voltage across an external resistor that is proportional to the bias current.  |
| 9            | SHUTDOWN   | Shutdown Driver Output. Voltage output to control an external transistor for optional shutdown circuitry.  |
| 10, 12       | GND        | Ground   |
| 11           | TX_FAULT   | Open-Collector Transmit Fault Indicator (Table 1)  |
| 13           | BIAS       | Laser Bias-Current Output  |
| 15           | OUT-       | Inverted Modulation-Current Output. IMOD flows into this pin when input data is low.   |
| 16           | OUT+       | Noninverted Modulation-Current Output. IMOD flows into this pin when input data is high.   |
| 18           | MD         | Monitor Photodiode Input. Connect this pin to the anode of a monitor photodiode. A capacitor to ground is required to filter the high-speed AC monitor photocurrent.   |
| 19           | APCFILT1   | Connect a capacitor (CAPC) between pin 19 (APCFILT1) and pin 20 (APCFILT2) to set the dominant pole of the APC feedback loop.  |
| 20           | APCFILT2   | (See pin 19)   |
| 21           | APCSET     | A resistor connected from this pin to ground sets the desired average optical power. The total capacitive load at the APCSET pin should be no more than 10pF. Minimize metal resistance for ground connections.                      |
| 22           | MODSET     | A resistor connected from this pin to ground sets the desired constant portion of the modulation current. The total capacitive load at the MODSET pin should be no more than 10pF. Minimize metal resistance for ground connections. |
| 23           | MODBCOMP   | Modulation-Current Compensation from Bias. Couples the bias current to the modulation current.<br>Mirrors IBIAS through an external resistor. Leave open for zero-coupling.  |
| 24           | TH_TEMP    | Threshold for Temperature Compensation. A resistor at this pin programs the temperature above which compensation is added to the modulation current.   |
| _            | EP         | Exposed Pad. Solder the exposed pad to the circuit board ground for specified thermal and electrical performance.  |





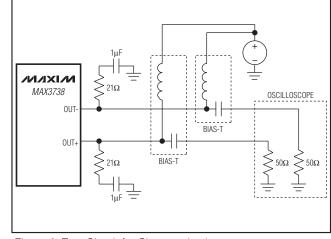


Figure 2. Test Circuit for Characterization

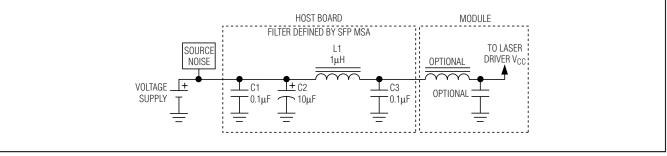


Figure 3. Supply Filter

### **Detailed Description**

The MAX3738 laser driver consists of three main parts: a high-speed modulation driver, biasing block with ERC, and safety circuitry. The circuit design is optimized for high-speed, low-voltage (+3.3V) operation (Figure 4).

#### **High-Speed Modulation Driver**

The output stage is composed of a high-speed differential pair and a programmable modulation current source. The MAX3738 is optimized for driving a 15 $\Omega$  load. The minimum instantaneous voltage required at OUT- is 0.7V for modulation currents up to 60mA and 0.75V for currents from 60mA to 85mA. Operation above 60mA can be accomplished by AC-coupling or with sufficient voltage at the laser to meet the driver output voltage requirement.

To interface with the laser diode, a damping resistor  $(R_{\mbox{\scriptsize D}})$  is required. The combined resistance damping

resistor and the equivalent series resistance (ESR) of the laser diode should equal 15 $\Omega$ . To further damp aberrations caused by laser diode parasitic inductance, an RC shunt network may be necessary. Refer to Application Note 274: *HFAN-02.0: Interfacing Maxim Laser Drivers with Laser Diodes* for more information.

At high data rates, any capacitive load at the cathode of a laser diode degrades optical output performance. Because the BIAS output is directly connected to the laser cathode, minimize the parasitic capacitance associated with the pin by using an inductor to isolate the BIAS pin parasitics from the laser cathode.

#### **Extinction Ratio Control**

The extinction ratio  $(r_e)$  is the laser on-state power divided by the off-state power. Extinction ratio remains constant if peak-to-peak and average power are held constant:

$$r_e = (2P_{AVG} + P_{P-P}) / (2P_{AVG} - P_{P-P})$$

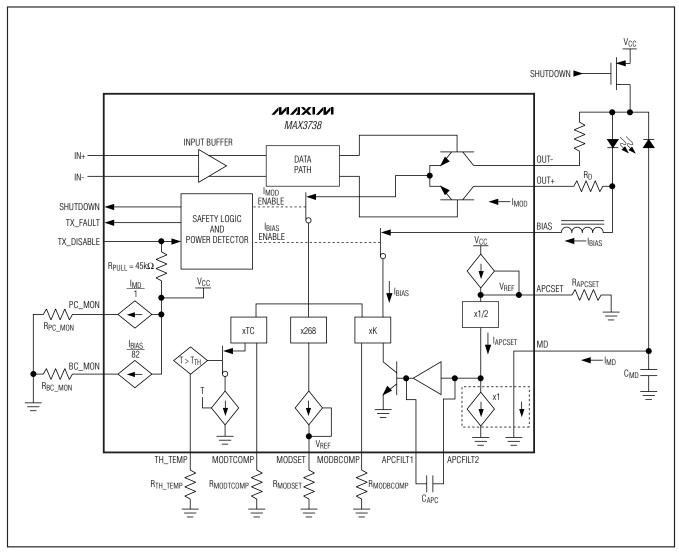


Figure 4. Functional Diagram

Average power is regulated using APC, which keeps constant current from a photodiode coupled to the laser. Peak-to-peak power is maintained by compensating the modulation current for reduced slope efficiency ( $\eta$ ) of laser over time and temperature:

$$P_{AVG} = I_{MD} / \rho_{MON}$$
  
 $P_{P-P} = \eta \times I_{MOD}$ 

Modulation compensation from bias increases the modulation current by a user-selected proportion (K) needed to maintain peak-to-peak laser power as bias current increases with temperature. Refer to Application Note 1119: *HFAN-02.2.1: Maintaining the Extinction Ratio of Optical Transmitters Using K-Factor Control* for details:

#### $K = \Delta I_{MOD} / \Delta I_{BIAS}$

This provides a first-order approximation of the current increase needed to maintain peak-to-peak power. Slope efficiency decreases more rapidly as temperature increases. The MAX3738 provides additional temperature compensation as temperature increases past a user-defined threshold (T<sub>TH</sub>).

MAX3738

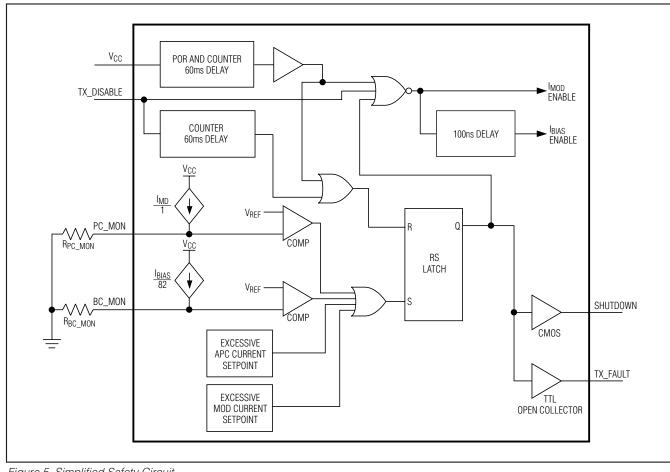


Figure 5. Simplified Safety Circuit

### **Table 1. Typical Fault Conditions**

| 1 | If any of the I/O pins are shorted to GND or V <sub>CC</sub> (single-point failure; see Table 2), and the bias current or the photocurrent exceeds the programmed threshold. |
|---|--|
| 2 | End-of-life (EOL) condition of the laser diode. The bias current and/or the photocurrent exceed the programmed threshold.  |
| 3 | Laser cathode is grounded and photocurrent exceeds the programming threshold.  |
| 4 | No feedback for the APC loop (broken interconnection, defective monitor photodiode), and the bias current exceeds the programmed threshold.                                  |

**MAX3738** 

### Table 2. Circuit Responses to Various Single-Point Faults

| PIN        | CIRCUIT RESPONSE TO OVERVOLTATGE OR<br>SHORT TO V <sub>CC</sub>  | CIRCUIT RESPONSE TO UNDERVOLTAGE OR<br>SHORT TO GROUND   |  |  |  |  |  |
|------------|--|--|--|--|--|--|--|
| TX_FAULT   | Does not affect laser power.   | Does not affect laser power.   |  |  |  |  |  |
| TX_DISABLE | Modulation and bias currents are disabled.   | Normal condition for circuit operation.  |  |  |  |  |  |
| IN+        | The optical average power increases, and a fault occurs if V <sub>PC_MON</sub> exceeds the threshold. The APC loop responds by decreasing the bias current.        | The optical average power decreases, and the APC loop responds by increasing the bias current. A fault state occurs if $V_{BC_MON}$ exceeds the threshold voltage. |  |  |  |  |  |
| IN-        | The optical average power decreases and the APC loop responds by increasing the bias current. A fault state occurs if $V_{BC\_MON}$ exceeds the threshold voltage. | The optical average power increases and a fault occurs if V <sub>PC_MON</sub> exceeds the threshold. The APC loop responds by decreasing the bias current.         |  |  |  |  |  |
| MD         | This disables bias current. A fault state occurs.  | The APC circuit responds by increasing the bias current until a fault is detected; then a fault* state occurs.   |  |  |  |  |  |
| SHUTDOWN   | Does not affect laser power. If the shutdown circuitry is used, the laser current is disabled.   | Does not affect laser power.   |  |  |  |  |  |
| BIAS       | In this condition, the laser forward voltage is 0V and no light is emitted.  | Fault state* occurs. If the shutdown circuitry is used, the laser current is disabled.   |  |  |  |  |  |
| OUT+       | The APC circuit responds by increasing the bias current until a fault is detected; then a fault state* occurs.   | Fault state* occurs. If the shutdown circuitry is used, the laser current is disabled.   |  |  |  |  |  |
| OUT-       | Does not affect laser power.   | Does not affect laser power.   |  |  |  |  |  |
| PC_MON     | Fault state* occurs.   | Does not affect laser power.   |  |  |  |  |  |
| BC_MON     | Fault state* occurs.   | Does not affect laser power.   |  |  |  |  |  |
| APCFILT1   | $I_{\text{BIAS}}$ increases until $V_{\text{BC}\_\text{MON}}$ exceeds the threshold voltage.   | $I_{\text{BIAS}}$ increases until $V_{\text{BC}\_\text{MON}}$ exceeds the threshold voltage.   |  |  |  |  |  |
| APCFILT2   | $I_{\text{BIAS}}$ increases until $V_{\text{BC}}$ MON exceeds the threshold voltage.   | $I_{\text{BIAS}}$ increases until $V_{\text{BC}\_\text{MON}}$ exceeds the threshold voltage.   |  |  |  |  |  |
| MODSET     | Does not affect laser power.   | Fault state* occurs.   |  |  |  |  |  |
| APCSET     | Does not affect laser power.   | Fault state* occurs.   |  |  |  |  |  |

\*A fault state asserts the TX\_FAULT pin, disables the modulation and bias currents, and asserts the SHUTDOWN pin.

Safety Circuitry The safety circuitry contains a disable input (TX\_DISABLE), a latched fault output (TX\_FAULT), and fault detectors (Figure 5). This circuitry monitors the operation of the laser driver and forces a shutdown if a fault is detected (Table 1). The TX\_FAULT pin should be pulled high with a  $4.7k\Omega$  to  $10k\Omega$  resistor to V<sub>CC</sub> as required by the SFP MSA. A single-point fault can be a short to V<sub>CC</sub> or GND. See Table 2 to view the circuit response to various single-point failure. The transmit fault condition is latched until reset by a toggle or TX\_DISABLE or V<sub>CC</sub>. The laser driver offers redundant laser diode shutdown through the optional shutdown circuitry as shown in the Typical Application Circuit. This shutdown transistor prevents a single-point fault at the laser from creating an unsafe condition.

#### **Safety Circuitry Current Monitors**

The MAX3738 features monitors (BC\_MON, PC\_MON) for bias current (I<sub>BIAS</sub>) and photocurrent (I<sub>MD</sub>). The monitors are realized by mirroring a fraction of the currents and developing voltages across external resistors connected to ground. Voltages greater than V<sub>REF</sub> at PC\_MON or BC\_MON result in a fault state. For example, connecting a 100 $\Omega$  resistor to ground at each monitor output gives the following relationships:

 $V_{BC_MON} = (I_{BIAS} / 82) \times 100\Omega$ 

 $V_{PC}MON = I_{MD} \times 100\Omega$ 

External sense resistors can be used for high-accuracy measurement of bias and photodiode currents. On-chip isolation resistors are included to reduce the number of components needed to implement this function.



| PARAMETER                    | SYMBOL         | RELATION                                |
|------------------------------|----------------|---|
| Average Power                | Pavg           | $P_{AVG} = (P_0 + P_1) / 2$             |
| Extinction Ratio             | r <sub>e</sub> | $r_{e} = P_{1} / P_{0}$                 |
| Optical Power of a One       | P <sub>1</sub> | $P_1 = 2P_{AVG} \times r_e / (r_e + 1)$ |
| Optical Power of a Zero      | P <sub>0</sub> | $P_0 = 2P_{AVG} / (r_e + 1)$            |
| Optical Amplitude            | Pp-p           | $P_{P-P} = P_1 - P_0$                   |
| Laser Slope Efficiency       | η              | $\eta = P_{P-P} / I_{MOD}$              |
| Modulation Current           | IMOD           | $I_{MOD} = P_{P-P} / \eta$              |
| Threshold Current            | ITH            | P <sub>0</sub> at I I <sub>TH</sub>     |
| Bias Current<br>(AC-Coupled) | IBIAS          | IBIAS ITH + IMOD / 2                    |
| Laser to Monitor<br>Transfer | PMON           | I <sub>MD</sub> / Pavg                  |

#### **Table 3. Optical Power Relations**

**Note:** Assuming a 50% average input duty cycle and mark density.

### **Design Procedure**

When designing a laser transmitter, the optical output is usually expressed in terms of average power and extinction ratio. Table 3 shows relationships that are helpful in converting between the optical average power and the modulation current. These relationships are valid if the mark density and duty cycle of the optical waveform are 50%.

For a desired laser average optical power (P<sub>AVG</sub>) and optical extinction ratio ( $r_e$ ), the required bias and modulation currents can be calculated using the equations in Table 3. Proper setting of these currents requires knowledge of the laser to monitor transfer ( $\rho_{MON}$ ) and slope efficiency ( $\eta$ ).

#### Programming the Monitor-Diode Current Set Point

The MAX3738 operates in APC mode at all times. The bias current is automatically set so average laser power is determined by the APCSET resistor:

#### PAVG = IMD / PMON

The APCSET pin controls the set point for the monitor diode current. An internal current regulator establishes the APCSET current in the same manner as the MODSET pin. See the Photodiode Current vs. RAPCSET graph in the *Typical Operating Characteristics* and select the value of RAPCSET that corresponds to the required current at  $+25^{\circ}$ C.

 $I_{MD} = 1/2 \times V_{REF} / R_{APCSET}$ 

The laser driver automatically adjusts the bias to maintain the constant average power. For DC-coupled laser diodes:

#### Programming the Modulation Current with Compensation

Determine the modulation current from the laser slope efficiency:

$$I_{MOD} = 2 \times P_{AVG} / \eta \times (r_e - 1) / (r_e + 1)$$

The modulation current of the MAX3738 consists of a static modulation current ( $I_{MODS}$ ), a current proportional to I<sub>BIAS</sub>, and a current proportional to temperature. The portion of I<sub>MOD</sub> set by MODSET is established by an internal current regulator, which maintains the reference voltage of V<sub>REF</sub> across the external programming resistor. See the Modulation Current vs. R<sub>MODSET</sub> graph in the *Typical Operating Characteristics* and select the value of R<sub>MODSET</sub> that corresponds to the required current at +25°C:

 $I_{MOD} = I_{MODS} + K \times I_{BIAS} + I_{MODT}$  $I_{MODS} = 268 \times V_{REF} / R_{MODSET}$  $I_{MODT} = TC \times (T - T_{TH}) \qquad | T > T_{TH}$  $I_{MODT} = 0 \qquad | T \leq T_{TH}$ 

An external resistor at the MODBCOMP pin sets current proportional to I<sub>BIAS</sub>. Open circuiting the MODBCOMP pin can turn off the interaction between I<sub>BIAS</sub> and I<sub>MOD</sub>:

 $K = 1700 / (1000 + R_{MODBCOMP}) \pm 10\%$ 

If I<sub>MOD</sub> must be increased from I<sub>MOD1</sub> to I<sub>MOD2</sub> to maintain the extinction ratio at elevated temperatures, the required compensation factor is:

 $K = (I_{MOD2} - I_{MOD1}) / (I_{BIAS2} - I_{BIAS1})$ 

A threshold for additional temperature compensation can be set with a programming resistor at the TH\_TEMP pin:

 $T_{TH} = -70^{\circ}C + 1.45M\Omega / (9.2k\Omega + R_{TH_{TEMP}})^{\circ}C \pm 10\%$ 

The temperature coefficient of thermal compensation above  $T_{TH}$  is set by  $R_{MODTCOMP}$ . Leaving the MODTCOMP pin open disables additional thermal compensation:

 $TC = 1 / (0.5 + R_{MODTCOMP}(k\Omega)) \text{ mA/°C } \pm 10\%$ 

# Current Compliance ( $I_{MOD} \le 60mA$ ), DC-Coupled

The minimum voltage at the OUT+ and OUT- pins is 0.7V.

For:

VDIODE = Diode bias point voltage (1.2V typ)

 $R_L$  = Diode bias point resistance (5 $\Omega$  typ)

 $R_D$  = Series matching resistor (20 $\Omega$  typ)

For compliance:

 $\label{eq:VOUT+} \begin{array}{l} \mathsf{V}_{OUT+} = \mathsf{V}_{CC} - \mathsf{V}_{DIODE} - \mathsf{I}_{MOD} \times (\mathsf{R}_D + \mathsf{R}_L) - \\ \mathsf{I}_{BIAS} \times \mathsf{R}_L \geq 0.7 \mathsf{V} \end{array}$ 

#### Current Compliance (IMOD > 60mA), AC-Coupled

For applications requiring modulation current greater than 60mA, headroom is insufficient from proper operation of the laser driver if the laser is DC-coupled. To avoid this problem, the MAX3738's modulation output can be AC-coupled to the cathode of a laser diode. An external pullup inductor is necessary to DC-bias the modulation output at V<sub>CC</sub>. Such a configuration isolates laser forward voltage from the output circuitry and allows the output at OUT+ to swing above and below the supply voltage (V<sub>CC</sub>). When AC-coupled, the MAX3738 modulation current can be programmed up to 85mA. Refer to Application Note 274: *HFAN-02.0: Interfacing*  *Maxim Laser Drivers with Laser Diodes* for more information on AC-coupling laser drivers to laser diodes. For compliance:

 $V_{OUT+} = V_{CC} - I_{MOD} / 2 \times (R_D + R_L) \ge 0.75 V$ 

#### **Determine CAPC**

The APC loop filter capacitor (C<sub>APC</sub>) must be selected to balance the requirements for fast turn-on and minimal interaction with low frequencies in the data pattern. The low-frequency cutoff is:

#### $C_{APC}(\mu F) \cong 68 / (f_{3dB}(kHz) \times (\eta \times \rho_{MON})^{1.1})$

High-frequency noise can be filtered with an additional cap,  $C_{\mbox{MD}}$  from the MD pin to ground.

#### $C_{MD} \cong C_{APC} / 4$

The MAX3738 is designed so turn-on time is faster than 1ms for most laser gain values ( $\eta \times \rho_{MON}$ ). Choosing a smaller value of C<sub>APC</sub> reduces turn-on time. Careful balance between turn-on time and low-frequency cutoff may be needed at low data rates for some values of laser gain.

#### **Interface Models**

Figures 6 and 7 show simplified input and output circuits for the MAX3738 laser driver. If dice are used, replace package parasitic elements with bondwire parasitic elements.

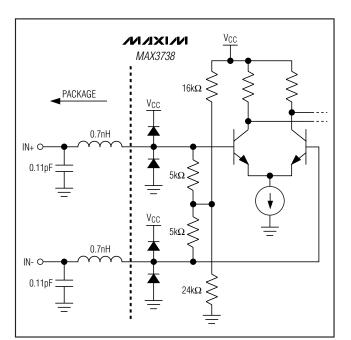


Figure 6. Simplified Input Structure

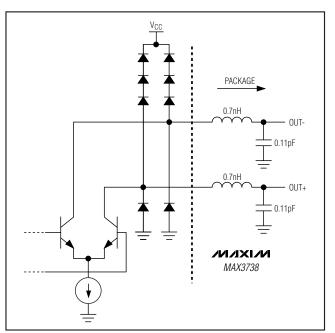


Figure 7. Simplified Output Structure

#### **Layout Considerations**

To minimize loss and crosstalk, keep the connections between the MAX3738 output and the laser diode as short as possible. Use good high-frequency layout techniques and multilayer boards with uninterrupted ground plane to minimize EMI and crosstalk. Circuit boards should be made using low-loss dielectrics. Use controlled-impedance lines for data inputs, as well as the module output.

#### Laser Safety and IEC 825

Using the MAX3738 laser driver alone does not ensure that a transmitter design is IEC 825 compliant. The entire transmitter circuit and component selections must be considered. Each customer must determine the level of fault tolerance required by their application, recognizing that Maxim products are not designed or authorized for use as components in systems intended for surgical implant into the body, for applications intended to support or sustain life, or for any other application where the failure of a Maxim product could create a situation where personal injury or death may occur.

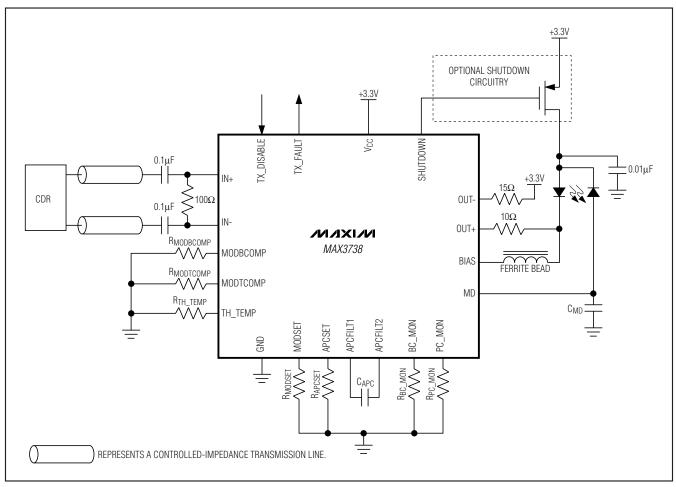
#### Exposed-Pad (EP) Package

The exposed pad on the 24-pin TQFN provides a very low thermal resistance path for heat removal from the IC. The pad is also electrical ground on the MAX3738 and should be soldered to the circuit board ground for proper thermal and electrical performance. Refer to Maxim Application Note 862: *HFAN-08.1: Thermal Considerations of QFN and Other Exposed-Paddle Packages* at **www.maxim-ic.com** for additional information.

#### **Chip Information**

PROCESS: SiGe/BiPOLAR

### **Typical Application Circuit**



### Package Information

For the latest package outline information and land patterns (footprints), go to <u>www.maxim-ic.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

| PACKAGE TYPE | PACKAGE CODE | OUTLINE NO.    | LAND PATTERN NO. |
|--------------|--------------|----------------|------------------|
| 24 TQFN-EP   | T2444-3      | <u>21-0139</u> | <u>90-0021</u>   |

### **Revision History**

| REVISION<br>NUMBER | REVISION<br>DATE | DESCRIPTION  | PAGES<br>CHANGED |  |  |
|--------------------|------------------|--|------------------|--|--|
| 0                  | 1/04             | Initial release.   |                  |  |  |
|                    |                  | Changed the data sheet from 1Gbps to 2.7Gbps to 155Mbps to 2.7Gbps.  | All              |  |  |
|                    |                  | Added the lead-free package to the Ordering Information table.   | 1                |  |  |
| 1                  | 7/05             | In the <i>Electrical Characteristics</i> table, added 622Mbps and 155Mbps conditions to the deterministic jitter parameter.  | 2                |  |  |
|                    |                  | Added the 100 $\Omega$ resistor to the <i>Typical Application Circuit</i> .  | 13               |  |  |
|                    |                  | Increased the maximum data rate 2.7Gbps to 4.25Gbps.   | All              |  |  |
|                    |                  | Added 4Gbps to the Applications for Fibre Channel SFF/SFP and GBIC transceivers.   | 1                |  |  |
| 2                  | 12/08            | Changed the derate factor for continuous power dissipation in the <i>Absolute Maximum Ratings</i> from 20.8mW/°C to 27.8mW/°C.   | 2                |  |  |
|                    |                  | Added new TOCs 4 and 5 to the Typical Operating Characteristics section.   | 4                |  |  |
|                    |                  | Changed VBG to VREF in Figure 4.   | 9                |  |  |
|                    |                  | Changed the transistor count from 1184 to 3754 in the Chip Information section.  | 14               |  |  |
|                    |                  | Added Lead Temperature and Soldering Temperature to the <i>Absolute Maximum Ratings</i> section.   | 2                |  |  |
|                    |                  | Changed Continuous Power Dissipation from $T_A = +85^{\circ}C$ to $+70^{\circ}C$ and $1805$ mW to 2222mW in the <i>Absolute Maximum Ratings</i> section.               | 2                |  |  |
| 3                  | 6/11             | Changed Bias-Current Monitor Ratio minimum, typical, and maximum values from [68, 79, 95] to [62, 76, 90] respectively in the <i>Electrical Characteristics</i> table. | 2                |  |  |
|                    |                  | Removed the condition from the Output Overshoot and Undershoot line in the <i>Electrical Characteristics</i> table.  | 2                |  |  |
|                    |                  | Replaced Figure 2 with new figure.   | 8                |  |  |
|                    |                  | Removed Transistor Count from Chip Information section.  | 14               |  |  |

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

16

**MAX3738** 

\_Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600